



**AP-377**

**APPLICATION  
NOTE**

**16-Mbit Flash Product Family  
Software Drivers  
28F016SA, 28F016SV,  
28F016XS, 28F016XD**

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# 16-Mbit FLASH PRODUCT FAMILY SOFTWARE DRIVERS

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## INTRODUCTION

### ABOUT THE CODE

This application note provides example software code for word writing, block erasing, and otherwise controlling Intel's 28F016SA, 28F016SV, 28F016XS and 28F016XD (hereafter referred to as 28F016SA) 16 Mbit symmetrically blocked memory components. Two programming languages are provided: high-level "C" for broad platform support, and more optimized ASM86 assembly. In many cases, the driver routines can be inserted "as is" into the main body of code being developed by the system software engineer. Extensive comments are included in each routine to facilitate adapting the code to specific applications.

The internal automation of the 28F016SA makes software timing loops unnecessary and results in platform-independent code. The following example code is designed to be executed in any type of memory and with all processor clock rates. C code can be used with many microprocessors and microcontrollers, while ASM86 assembly code provides a solution optimized for Intel microprocessors and embedded processors.

The 28F016SA, like the 28F008SA, is divided into 64 Kbyte blocks. Since the GSR and BSR are defined relative to the nearest preceding block beginning address, I often refer to this "block base" address in the comments.

#### Assumptions:

- Pointers (in C) or EDI offsets (in ASM86) are four (4) bytes long, providing a flat addressing space over the entire 28F016SA device. This implies the use of 386 or higher machines. If the code is to be run on a machine with a smaller address space, the code must be modified to include some sort of "windowing" scheme which maps segments of flash into system memory. The Intel 82365 is commonly used for this purpose.
- "Ints" are 16 bit and "longs" 32 bit in C.
- It is assumed that these pointers return a value equal to what they are pointing to. In other words, even though the pointer may be four (4) bytes long, this does not imply that incrementing the pointer by one will move the pointer four (4) bytes in memory. It is entirely dependent upon what the pointer is pointing to that determines how the increment will be effected. In the case of four (4) byte pointers and 16-bit ints, incrementing the pointer by one will effectively move the pointer two (2) bytes.
- There exists a function "set\_pin" which can set an individual 28F016SA pin, given the pin number.
- There exists a function "get\_pin" which can return the value of an individual 28F016SA pin, given the pin number.
- The C code can access a function which derives the corresponding block base address from any given address.
- BYTE# pin on the device determines whether addressing refers to words or bytes. I assume word writes/reads to a single device. With minor modifications this code can be adapted for a pair of 28F016SAs in Byte mode.
- 28F016SA commands can be written to any address in the block or device to be affected by that command.

Both the C and ASM86 code in this document contain the following routines, in this order:

```
CSR_word_byte_writes(compatible with 28F008SA)
CSR_block_erase(compatible with 28F008SA)
CSR_erase_suspend_to_read(compatible with
28F008SA)
lock_block
lock_status_upload_to_BSR
update_data_in_a_locked_block
add_data_in_a_locked_block
ESR_word_write
two_byte_write
ESR_page_buffer_write
ESR_block_erase
ESR_erase_all_unlocked_blocks
ESR_suspend_to_read_array
ESR_automatic_erase_suspend_to_write
ESR_full_status_check_for_data_write
ESR_full_status_check_for_erase
single_load_to_pagebuffer
sequential_load_to_pagebuffer
upload_device_information
RYBY_reconfiguration
page_buffer_swap
```

The names of these routines have been changed to more closely match the algorithms presented in the 28F016SA User's Manual (Order Number 297372). Please see Appendix A for a table documenting these changes.

## ABOUT THE 28F016SA

Companion product datasheets for the 28F016SA should be reviewed in conjunction with this application note for a complete understanding of the device.

The example code makes extensive use of bit-masking when interpreting the status registers. As a quick review, note that any bit in a register can be tested by bitwise ANDing the register with the appropriate power of two. Since all of the bits other than the one being

tested are masked out, testing the resulting byte for truth is the same as testing the desired bit for truth. For example, if a register contains 01001010, the test for bit 3 would be ANDing the register with 00001000, or hex 8, and testing the result for truth:

<b>Binary</b>	<b>Hex</b>	
01001010	4A	Register
& 00001000	& 08	Mask for bit 3
= 00001000	= 08	Result

In this case the result byte is true, indicating that bit 3 in the register was a 1.

The meanings of the individual bits of these registers is presented here for reference. Note that there are two status register spaces, both of which are distinct from the flash memory array address space. In the CSR space, the CSR is mapped to every address. In the ESR space, the GSR is mapped two words above the base of each 64K byte block, i.e. to addresses 2, 8002H, 10002H, etc. (in word mode), while each BSR is similarly mapped one word above the base of each 64K byte block to locations 1, 8001H, 10001H, etc. (in word mode), each BSR reflecting the status of its own block.

CSR.7	Write State Machine Status	1 = ready 0 = busy
CSR.6	Erase-suspend Status	1 = erase suspended 0 = erase in progress/completed
CSR.5	Erase Status	1 = error in block erase 0 = successful block erase
CSR.4	Data-write Status	1 = error in data write 0 = successful data write
CSR.3	V <sub>PP</sub> Status	1 = V <sub>PP</sub> low detect/ operation aborted 0 = V <sub>PP</sub> OK when operation occurred
CSR.2	Reserved for future use	
CSR.1	Reserved for future use	
CSR.0	Reserved for future use	

GSR.7	Write State Machine Status	1 = ready 0 = busy
GSR.6	Operation-suspend Status	1 = operation suspended 0 = operation in progress/completed
GSR.5	Device Operation Status	1 = operation unsuccessful 0 = operation successful or running
GSR.4	Device Sleep Status	1 = device in sleep 0 = device not in sleep
GSR.3	Queue Status	1 = queue full 0 = queue available
GSR.2	Page Buffer Availability	1 = one/two page buffers available 0 = no page buffers available
GSR.1	Page Buffer Status	1 = selected page buffer ready 0 = selected page buffer busy
GSR.0	Page Buffer Select Status	1 = page buffer 1 selected 0 = page buffer 0 selected
BSR.7	Block Status	1 = ready 0 = busy
BSR.6	Block-lock Status	1 = block unlocked for write/erase 0 = block locked to write/erase
BSR.5	Block Operation Status	1 = error in block operation 0 = successful block operation
BSR.4	Block Operation Abort Status	1 = block operation aborted 0 = block operation not aborted
BSR.3	Queue Status	1 = device queue full 0 = device queue available
BSR.2	V <sub>PP</sub> Status	1 = V <sub>PP</sub> low detected 0 = V <sub>PP</sub> OK when operation occurred
BSR.1	Reserved for future use	
BSR.0	Reserved for future use	

## 28F016SA Commands

The 28F016SA command set is a superset of the 28F008SA command set, giving existing 28F008SA code the ability to run on the 28F016SA with minimal modifications.

### 28F008SA-Compatible Commands

00	invalid/reserved
20	single block erase
40	word/byte write
50	clear status registers
70	read CSR
90	read ID codes
B0	erase suspend
D0	confirm/resume
FF	read flash array

### 28F016SA Performance-Enhancement Commands

0C	page buffer write to flash
71	read GSR and BSRs (i.e. the ESR)
72	page buffer swap
74	single load to page buffer
75	read page buffer
77	lock block
80	abort
96,xx	RY/BY# reconfiguration and SFI configuration (28F016XS)
97	upload BSRs with lock bit
99	upload device information
A7	erase all unlocked blocks
E0	sequential load to page buffer
F0	sleep
FB	two-byte write

## 28F016XD and 28F016XS Feature Sets

The following features are not supported on the 28F016XD and 28F016XS Fast Flash memories (as compared to the 28F016SA/SV/32SA FlashFile™ memories):

- All page buffer operations (read, load, program, Upload Device Information)
- Command queuing
- Erase All Unlocked Blocks and Two-Byte Write
- Software Sleep and Abort
- RY/BY# reconfiguration via the Device Configuration command

```

"C" DRIVERS
/*********************************************************************
/* Copyright Intel Corporation, 1993
/* File : stddefs.h
/* Standard definitions for C Drivers for the 28F016SA/SV/XS/XD Flash
/* memory components
/* Author : Taylor Gautier, Intel Corporation
/* Revision 1.0, 23 September 1994
/********************************************************************

/*****
/* pin values
/*****
#define LOW          0
#define HIGH         1

/*****
/* error codes
/*****
#define NO_ERROR      0
#define VPP_LOW       1
#define OP_ABORTED    2
#define BLOCK_LOCKED  3
#define COMMAND_SEQ_ERROR 4
#define WP_LOW        5

/*****
/* bit masks
/*****
#define BIT_0          0x0001
#define BIT_1          0x0002
#define BIT_2          0x0004
#define BIT_3          0x0008
#define BIT_4          0x0010
#define BIT_5          0x0020
#define BIT_6          0x0040
#define BIT_7          0x0080

#define LOW_BYT          0x00FF
#define HIGH_BYT         0xFF00

/*****
/* RY/BY# enable modes
/*****
#define RYBY_ENABLE_TO_LEVEL 1
#define RYBY_PULSE_ON_WRITE  2
#define RYBY_PULSE_ON_ERASE  3
#define RYBY_DISABLE        4

/*****
/* pin numbers
/*****
#define WPB 56
/* Write Protect pin (active low) is pin number 56 on standard
/* pinout of 28F016SA.

#define VPP 15
/* Vpp pin is pin number 15 on standard pinout of 28F016SA.
*/

```

292126-1

```
*****  
/* Copyright Intel Corporation, 1993 */  
/* File : drivers.c */  
/* Example C Routines for 28F016SA/SV/XS/XD Flash memory components */  
/* Original Author : Patrick Killelea, Intel Corporation */  
/* Revised By : Taylor Gautier, Intel Corporation */  
/* Revision 2.0, 23 September 1994 */  
/* */  
/* NOTE: BYTE# pin on the device determines whether addressing */  
/* refers to words or bytes. I assume word mode. */  
/* NOTE: A 28F016SA command can be written to any address in the */  
/* block or device to be affected by that command. */  
*****  
#include <stdio.h>  
#include "stddefs.h"  
  
void set_pin(int pin, int level)  
{  
/* set_pin is an implementation-dependent function which sets a */  
/* given pin on the standard 28F016SA pinout HIGH = 1 or LOW = 0. */  
}  
  
int get_pin(int pin)  
{  
/* get_pin is an implementation-dependent function which returns a */  
/* given pin on the standard 28F016SA pinout HIGH = 1 or LOW = 0 */  
}  
  
int *base(int *address)  
{  
/* base is an implementation-dependent function which takes an */  
/* address in the flash array and returns a pointer to the base */  
/* of that 64K byte block. */  
}  
  
char *byte_base(char *address)  
{  
/* byte version of base function described above */  
}
```

292126-2

```
int CSR_word_byte_writes(int *address, int data)
{
/* This procedure writes a byte to the 28F016SA.          */
/* It also works with the 28F008SA.          */
int CSR;
/* CSR variable is used to return contents of CSR register. */

*address = 0X1010;
/* Word Write command
*address = data;
/* Actual data write to flash address.
while(!(BIT_7 & *address));
/* Poll CSR until CSR.7 = 1 (WSM ready)

CSR = *address;
/* Save CSR before clearing it.
*address = 0X5050;
/* Clear Status Registers command
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode.
return(CSR);
/* Return CSR to be checked for status of operation.
}
```

292126-3

```
int CSR_block_erase(int *address)
{
/* This procedure erases a 64K byte block on the 28F016SA.          */
int CSR;
/* CSR variable is used to return contents of CSR register.          */

*address = 0X2020;
/* Single Block Erase command                                         */
*address = 0XD0D0;
/* Confirm command                                                 */
*address = 0xD0D0;
/* Resume command, per latest errata update                         */
while(!(BIT_7 & *address))
/* Poll CSR until CSR.7 = 1 (WSM ready)                            */
{
/* System may issue an erase suspend command (B0[B0]) here to read data */
/* from a a different block.                                         */
};

/* At this point, CSR.7 is 1, indicating WSM is not busy.          */
/* Note that we are still reading from CSR by default.          */
CSR = *address;
/* Save CSR before clearing it.                                         */
*address = 0X5050;
/* Clear Status Registers command                                     */
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(CSR);
/* Return CSR to be checked for status of operation.                */
}
/* If a write has been queued, an automatic erase suspend occurs to write */
/* to a different block.                                                 */

```

292126-4

```
int CSR_erase_suspend_to_read(int *read_address, int *erase_address, int
*result)
{
/* This procedure suspends an erase operation to do a read. */
int CSR;
/* CSR variable is used to return contents of CSR register. */

/* Assume erase is underway in block beginning at erase_address. */
*erase_address = 0XB0B0;
/* Erase Suspend command */
while(!(BIT_7 & *erase_address));
/* Poll CSR until CSR.7 = 1 (WSM ready) */
if (BIT_6 & *erase_address) {
/* If CSR.6 = 1 (erase incomplete)
 *erase_address = 0xFFFF;
/* Read Flash Array command
*result = *read_address;
/* Do the actual read. Any number of reads can be done here. */
*erase_address = 0XD0D0;
/* Erase Resume command */
} else {
/*erase_address = 0xFFFF;
/* Read Flash Array command
*result = *read_address;
/* Do the actual read. Any number of reads can be done here.
}
*erase_address = 0x7070;
/* Read CSR command
CSR = *erase_address;
/* Save CSR before clearing it.
*erase_address = 0X5050;
/* Clear Status Registers command
return(CSR);
/* Return CSR to be checked for status of operation.
}
```

292126-5

```
int lock_block(int *lock_address)
/* This procedure locks a block on the 28F016SA. */
{
int ESR;
/* ESR variable is used to return contents of GSR and BSR. */

int *block_base = base(lock_address);
/* Find pointer to base of block being locked. */

*lock_address = 0X7171;
/* Read Extended Status Registers command */
while (BIT_3 & *(block_base + 2));
/* Poll GSR until GSR.3 = 0 (queue available). */
set_pin(WPB, HIGH);
/* Disable write protection by setting WPB high. */
set_pin(VPP, HIGH);
/* Enable Vpp, wait for ramp if necessary in this system. */
*lock_address = 0X7777;
/* Lock Block command */
*lock_address = 0XD0D0;
/* Confirmation command */
*lock_address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 2)));
/* GSR is 2 words above 0; poll GSR until GSR.7 = 1 (WSM ready). */

ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value. */
*lock_address = 0X5050;
/* Clear Status Registers command */
*lock_address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode.
return(ESR);
}
```

292126-6

```
int lock_status_upload_to_BSR(int *address)
/* This procedure uploads status information into the BSR from non-      */
/* volatile status bits.                                              */
{
int ESR;
/* ESR variable is used to return contents of GSR and BSR.          */
int *block_base = base(address);
/* Find pointer to base of 32K word block.                            */
*address = 0X7171;
/* Read Extended Status Registers command                           */
while (BIT_3 & *(block_base + 2));
/* Poll GSR until GSR.3 = 0 (queue available).                      */
*address = 0X9797;
/* Lock-status Upload command                                         */
*address = 0XD0D0;
/* Confirmation command                                              */
*address = 0X7171;
/* Read Extended Status Registers command                           */
while (!(BIT_7 & *(block_base + 2)));
/* Poll GSR until GSR.7 = 1 (WSM not busy)                           */
ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value.      */
*address = 0X5050;
/* Clear Status Registers command                                     */
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(ESR);
}
```

292126-7

```
int update_data_in_a_locked_block()
{
/* This routine is implemented as pseudo-code to provide an example of      */
/* implemeting the flowchart Updating Data in a Locked Block from the      */
/* 28F016SA User's Manual                                                 */
/*                                                               */
set_pin(WPB, HIGH);                                */
/* set WP# high                                         */
block_erase_with_CSR(block_address);               */
/* erase block                                         */
set_pin(WPB, LOW);                                */
/* set WP# low                                         */
WriteNewData();                                     */
/* Use one of Word/Byte Write, Two-Byte Write or Page Buffer Write to Flash*/
lock_block(block_address);                         */
/* lock block if desired                                */
}

int add_data_in_a_locked_block()
{
/* This routine is implemented as pseudo-code to provide an example of      */
/* implemeting the flowchart Updating Data in a Locked Block from the      */
/* 28F016SA User's Manual                                                 */
/*                                                               */
set_pin(WPB, HIGH);                                */
/* set WP# high                                         */
WriteNewData();                                     */
/* Use one of Word/Byte Write, Two-Byte Write or Page Buffer Write to      */
/* Flash                                         */
set_pin(WPB, LOW);                                */
/* set WP# low                                         */
}
```

292126-8

```
int ESR_word_write(int *write_address, int *data, int word_count)
/* This procedure writes a word to the 28F016SA. */ 
{
int counter, ESR;
/* counter is used to loop through data array */ 
/* ESR variable is used to return contents of GSR and BSR. */ 
int *block_base = base(write_address);

for (counter = 0; counter < word_count; counter++) {
    *write_address = 0X7171;
    /* Read Extended Status Registers command */ 
    while (BIT_3 & *(block_base + 1));
    /* Poll BSR until BSR.3 of target address = 0 (queue available). */ 
    /* BSR is 1 word above base of target block in status reg space. */ 
    *write_address = 0X1010;
    /* Write word command */ 
    *write_address = data[counter];
    /* Write actual data. */ 
}

*write_address = 0X7171;
/* Read Extended Status Registers command */ 
while (!(BIT_7 & *(block_base + 1)));
/* Poll BSR until BSR.7 of target address = 1 (block ready). */ 
ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value. */ 
*write_address = 0X5050;
/* Clear Status Registers command */ 
*write_address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */ 
return(ESR);
}
```

292126-9

```
int two_byte_write(char *address, char *data, int byte_count)
/* This routine is used when BYTE# is low, i.e. the 28F016SA          */
/* is in byte mode, to emulate a word write.                         */
/* Because of this, commands are given as 0x00XY instead of 0xXYXY as in  */
/* the rest of the code presented here.                                */
/* *data is a byte array containing the low byte, high byte consecutively of */
/* each word.                                                       */
{
int counter, ESR;
/* ESR variable is used to return contents of GSR and BSR.          */
char *block_base = byte_base(address);
/* Find pointer to base of block.                                     */

for (counter = 0; counter < byte_count; counter++) {
    *address = 0X0071;
    /* Read Extended Status Registers command                         */
    while (BIT_3 & *(block_base + 2));
    /* Poll BSR until BSR.3 of target address = 0 (queue available). */
    *address = 0X00FB;
    /* Two-byte Write command                                     */
    *address = data[counter++];
    /* Load one byte of data register; A0 = 0 loads low byte, A1 high */
    *address = data[counter];
    /* 28F016SA automatically loads alternate byte of data register */
}

/* Write is initiated. Now we poll for successful completion.          */
*address = 0X0071;
/* Read Extended Status Registers command                         */
while (!(BIT_7 & *(block_base + 2)));
/* Poll BSR until BSR.7 of target address = 1 (block ready).        */
/* BSR is 1 word above base of target block in status reg space. */

ESR = (*(block_base + 4) << 8) + (*(block_base + 2) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value.      */
*address = 0X0050;
/* Clear Status Registers command                                     */
*address = 0x00FF;
/* Write FFH after last operation to reset device to read array mode. */
return(ESR);
}
```

292126-10

```

int ESR_pagebuffer_write(int *address, int word_count)
/* This procedure writes from page buffer to flash. */
{
/* This routine assumes page buffer is already loaded. */
/* Address is where in flash array to begin writing. */
/* Low byte of word count word_count must be 127 or fewer, high must be 0. */
/* High byte of word count exists for future Page Buffer expandability. */
int ESR;
/* ESR variable is used to return contents of GSR and BSR. */
int *block_base = base(address);
/* Find pointer to base of block to be written. */

*address = 0X7171;
/* Read Extended Status Registers command */
while (BIT_3 & *(block_base + 1));
/* Poll BSR until BSR.3 of target address = 0 (queue available). */
*address = 0X0C0C;
/* Page Buffer Write to Flash command */
*address = word_count;
/* high byte is a don't care, write the low byte */
*address = 0;
/* write high byte of word_count which must be 0 (reserved for future use) */
*address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 1)));
/* Poll BSR until BSR.7 of target address =1 (block ready). */

ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value. */
*address = 0x5050;
/* Clear Status Registers command */
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(ESR);
}

```

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```
int ESR_block_erase(int *erase_address)
/* This procedure erases a block on the 28F016SA. */
{
int ESR;
/* ESR variable is used to return contents of GSR and BSR. */
int *block_base = base(erase_address);
/* Find address of base of block being erased. */

*erase_address = 0X7171;
/* Read Extended Status Registers command */
while (BIT_3 & *(block_base + 1));
/* Poll BSR until BSR.3 of erase_address = 0 (queue available). */
/* BSR is 1 word above base of target block in ESR space. */

*erase_address = 0X2020;
/* Single Block Erase command */
*erase_address = 0XD0D0;
/* Confirm command */
*erase_address = 0xD0D0;
/* Resume command, per latest errata update */
*erase_address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 1)));
/* Poll BSR until BSR.7 of target erase_address = 1 (block ready). */

ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value. */
*erase_address = 0X5050;
/* Clear Status Registers command */
*erase_address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(ESR);
}
```

292126-12

```

int ESR_erase_all_unlocked_blocks(int *device_address, long *failure_list)
/* This procedure erases all the unlocked blocks on a 28F016SA. */
{
int GSR;
/* Return value will contain GSR in both top and bottom byte. */
/* 32 bit long pointed to by failure_list is used to return map
/* of block failures, each bit representing one block's status. */
/* device_address points to base of chip. */
int block;
/* block is used to hold block count for loop through blocks. */
long power = 1;

*failure_list = 0;
/* Initialize all 32 bits of failure list long to 0. */
*device_address = 0X7171;
/* Read Extended Status Registers */
while (BIT_3 & *(device_address + 1));
/* Poll BSR until BSR.3 of target address = 0 (queue available). */
*device_address = 0XA7A7;
/* Full-chip erase command */
*device_address = 0XD0D0;
/* Confirm command */
*device_address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(device_address + 2)));
/* Poll GSR until GSR.7 = 1 (WSM ready) */

for (block = 0; block < 0X0020; block++)
{
    /* Go through blocks, looking at each BSR.5 for operation failure */
    /* and setting appropriate bit in long pointed to by failure list. */
    if (BIT_5 & *(device_address + block * 0X8000 + 1))
        /* Multiply block by 32K words to get to the base of each block. */
        *failure_list += power;
        /* If the block failed, set that bit in the failure list. */
        power = power << 1;
        /* Increment to next power of two to access next bit. */
}

GSR = *(device_address + 2);
*device_address = 0X5050;
/* Clear Status Registers command */
*device_address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode.
return(GSR);
}

```

292126-13

```
int ESR_suspend_to_read_array(int *address,int *result)
/* This procedure suspends an erase on the 28F016SA. */
{
/* Address is assumed to point to location to be read. */
/* result is used to hold read value until procedure is complete. */
int ESR;
/* ESR variable is used to return contents of GSR and BSR. */
int *block_base = base(address);

*address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 1)));
/* Poll BSR until BSR.7 of target address = 1 (block ready). */
/* BSR is 1 word above base of target block in ESR space. */
*address = 0XB0B0;
/* Operation Suspend command */
*address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 2)));
/* Poll GSR until GSR.7 = 1 (WSM ready). */
if (BIT_6 & *(block_base + 2)) {
/* GSR.6 = 1 indicates an operation was suspended on this device,
   *address = 0xFFFF;
   /* Read Flash Array command
   *result = *address;
   /* Read the data.
   *address = 0XD0D0;
   /* Resume the operation.
} else {
   *address = 0xFFFF;
   /* Read Flash Array command
   *result = *address;
   /* Read the data.
}

*address = 0x7171;
/* Read Extended Status Registers command */
ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value.
*address = 0X5050;
/* Clear Status Registers command
return(ESR);
}
```

292126-14

```

int ESR_automatic_erase_suspend_to_write(int *write_address, int
*erase_address, int data)
/* This procedure writes to one block while another is erasing. */
{
int ESR;
/* ESR variable is used to return contents of GSR and BSR. */
int * block_base = base(erase_address);
/* Find pointer to base of block being erased. */

*erase_address = 0X7171;
/* Read Extended Status Register command */
while (BIT_3 & *(block_base + 1));
/* Poll BSR until BSR.3 of target address = 0 (queue available). */
/* BSR is 1 word above base of target block in ESR space. */
*erase_address = 0X2020;
/* Erase Block command */
*erase_address = 0XD0D0;
/* Confirm command */
*erase_address = 0X7171;
/* Read Extended Status Register command */
while (BIT_3 & *(block_base + 1));
/* Poll BSR until BSR.3 of target address = 0 (queue available). */
/* BSR is 1 word above base of target block in ESR space. */
*write_address = 0X4040;
/* Word Write command */
*write_address = data;
/* Write actual data. */
/* Erase suspends, write takes place, then erase resumes. */
*erase_address = 0X7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 1)));
/* Poll BSR until BSR.7 of erase address = 1 (block ready). */
/* BSR is 1 word above base of target block in status reg space. */

ESR = (*(block_base + 2) << 8) + (*(block_base + 1) & LOW_BYTE);
/* Put GSR in top byte and BSR in bottom byte of return value. */
*block_base = 0X5050;
/* Clear Status Registers command */
*block_base = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(ESR);
}

```

292126-15

```
int ESR_full_status_check_for_data_write(int *device_address)
{
    int errorcode;

    *device_address = 0x7171;
    /* Read Extended Status Registers command */
    while (!(BIT_7 & *(device_address + 2))) ;
    /* Poll GSR until GSR.7 = 1 (WSM ready) */
    /* to make sure data is valid */

    if (*(device_address + 1) & BIT_2) errorcode = VPP_LOW;
    /* BSR.2 = 1 indicates a Vpp Low Detect */
    else if (*(device_address + 1) & BIT_4) errorcode = OP_ABORTED;
    /* BSR.4 = 1 indicates an Operation Abort */

    else if (get_pin(WPB) == LOW) errorcode = NO_ERROR;
    else if (*(device_address + 1) & BIT_6) errorcode = BLOCK_LOCKED;
    /* BSR.6 = 1 indicates the Block was locked */
    else errorcode = NO_ERROR;

    while (!(BIT_7 & *(device_address + 2))) ;
    /* Poll GSR until GSR.7 = 1 (WSM ready) */
    /* make sure chip is ready to accept command */

    *device_address = 0x5050;
    /* Clear Status Registers */

    return errorcode;
}
```

292126-16

```
int ESR_full_status_check_for_erase(int *device_address)
{
    int errorcode = NO_ERROR;

    *device_address = 0x7171;
    /* Read Extended Status Registers command */ 
    while (!(BIT_7 & *(device_address + 2)));
    /* Poll GSR until GSR.7 = 1 (WSM ready) */ 
    /* make sure command completed */ 
    if (*(device_address + 1) & BIT_2) errorcode = VPP_LOW;
    /* BSR.2 = 1 indicates a Vpp Low Detect */ 
    else if (*(device_address + 1) & BIT_4) errorcode = OP_ABORTED;
    /* BSR.4 = 1 indicates an Operation Abort */ 
    else if (get_pin(WPB) == LOW && !(*device_address + 1) & BIT_6))
        errorcode = BLOCK_LOCKED;
    /* BSR.6 = 0 indicates the Block was locked */ 
    if (errorcode == NO_ERROR) {
        *device_address = 0x7070;
        /* Read Compatible Status Register */ 
        if ((*device_address & BIT_4) && (*device_address & BIT_5))
            /* CSR.4 and CSR.5 == 1 indicate a command sequence error */ 
            errorcode = COMMAND_SEQ_ERROR;
    }

    while (!(BIT_7 & *(device_address + 2)));
    /* Poll GSR until GSR.7 = 1 (WSM ready) */ 
    /* make sure device is ready */ 

    *device_address = 0x5050;
    /* Clear Status Registers command */ 

    return errorcode;
}
```

292126-17

```
void single_load_to_pagebuffer(int *device_address, char *address, int data)
/* This procedure loads a single byte or word to a page buffer.          */
/* device_address points to base of chip.                                */
{
    *device_address = 0X7171;
    /* Read Extended Status Registers command                           */
    while (!(BIT_2 & *(device_address + 2)));
    /* Poll GSR until GSR.2 = 1 (page buffer available)                 */
    *device_address = 0X7474;
    /* Single Load to Page Buffer command                                */
    *address = data;
    /* Actual write to page buffer                                     */
    /* This routine does not affect status registers.                  */
    *address = 0xFFFF;
    /* Write FFH after last operation to reset device to read array mode. */
}
```

292126-18

```
void sequential_load_to_pagebuffer(int *device_address, char *start_address,
int word_count, int* data)
/* This procedure loads multiple words to a page buffer. */
/* device_address points to base of chip. */
{
/* Low byte of word_count must be 127 or fewer, high must be 0. */
/* word_count is zero-based counting, i.e word_count == 0 loads 1 word, */
/* word_count == 1 loads 2 words etc. */
/* High byte of word_count exists for future Page Buffer expandability. */
char counter;
/* counter is used to keep track of words written. */

*device_address = 0X7171;
/* Read Extended Status Registers command */
while (BIT_2 & *(device_address + 2));
/* Poll GSR until GSR.2 = 0 (page buffer available). */
*device_address = 0XE0E0;
/* Sequential Page Buffer Load command */
*start_address = word_count;
*start_address = 0;
/* Automatically loads high byte of count register */
for (counter = 0; counter <= word_count; counter++)
    *(start_address + counter) = data[counter];
/* Loop through data, writing to page buffer. */
/* This routine does not affect status registers. */
*device_address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode.
}
```

292126-19

```
int upload_device_information(int *address)
/* This procedure uploads the device revision number to the variable DRC. */
/* This implementation differs in that it does not loop as in the */
/* algorithm. This is so the calling routine can have a chance to do */
/* error checking instead of looping forever waiting for the device */
/* complete the operation. */
{
int DRC = 0;
/* DRC variable is used to return device revision status. */
int *block_base = base(address);
/* Find pointer to base of 32K word block. */

*address = 0x7171;
/* Read Extended Status Registers command */
while ((BIT_3 & *(block_base + 2)) && (!(BIT_7 & *(block_base + 2)))); /* */
/* Poll GSR until GSR.3 = 0 (queue available) and GSR.7 = 1 */
/* (WSM available). */
*address = 0x9999;
/* Device information Upload command */
*address = 0xD0D0;
/* Confirmation command */
*address = 0x7171;
/* Read Extended Status Registers command */
while (!(BIT_7 & *(block_base + 2)));
/* Poll GSR until GSR.7 = 1 (WSM not busy) */
if (BIT_5 & *(block_base+2)) return ((*(block_base+2) & HIGH_BYTE) << 8);
/* if GSR.5 = 1 operation was unsuccessful. Return GSR and 0 in DRC */
*address = 0X7272;
/* Swap page buffer to bring buffer with status information to top. */
*address = 0X7575;
/* Read Page Buffer command */
DRC = (*(block_base + 2) & 0xFF00 << 8) + (*(block_base + 3) & LOW_BYTE);
/* Put GSR in top byte of return value. */
/* User should check GSR for operation success */
/* Put device revision code in bottom byte of return value. */
/* Note that device revision code was read from word 3 in page buffer. */
*address = 0x5050;
/* Clear Status registers command */
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode. */
return(DRC);
}
```

292126-20

```

int RYBY_reconfigure(int *address, int mode)
{
    /* this procedure changes the RY/BY# configuration mode to the given mode */
    int GSR;
    /* the GSR variable is used to return the value of the GSR */

    *address = 0x7171;
    /* Read Extended Registers command */
    while (BIT_3 & *(address+2));
    /* Poll GSR until GSR.3 = 0 (queue available) */
    *address = 0x9696;
    /* Enable RY/BY# configuration, next command configures RY/BY# */
    switch (mode) {
        case RYBY_ENABLE_TO_LEVEL:
            *address = 0x0101;
            /* Enable RY/BY# to level mode */
            break;

        case RYBY_PULSE_ON_WRITE:
            *address = 0x0202;
            /* Enable RY/BY# to pulse on write */
            break;

        case RYBY_PULSE_ON_ERASE:
            *address = 0x0303;
            /* Enable RY/BY# to pulse on erase */
            break;

        case RYBY_DISABLE:
        default:
            *address = 0x0404;
            /* Enable RY/BY# to disable */
            break;
    }
    *address = 0X7171;
    /* Read Extended Status Registers command */
    while (!(BIT_7 & *(address + 2)));
    /* Poll GSR until GSR.7 = 1 (WSM ready) */
    GSR = *(address+2) & LOW_BYTE;
    /* put GSR into low byte of return value */
    *address = 0x5050;
    /* Clear Status registers command */
    *address = 0xFFFF;
    /* Write FFH after last operation to reset device to read array mode.
    return (GSR);
}

```

292126-21

```
int page_buffer_swap(int *address)
{
/* This routine attempts to swap the page buffers, returning the value of */
/* the GSR before the operation in the upper byte and the value of the GSR */
/* after the operation in the lower byte for comparison */
/* For operation to be successful, the following must be true : */
/* (before) GSR.0 = (after) !GSR.0 */
/* (after) GSR.5 = 0 */
int GSR;
/* GSR variable is used to return contents of GSR before and after */
/* operation */

*address = 0x7171;
/* Read Extended Registers command */
GSR = *(address+2) << 8;
/* Put GSR into upper byte before page buffer swap */
*address = 0x7272;
/* write Page Buffer Swap command */
GSR |= (*address+2) & LOW_BYTE;
/* Put GSR after operation into low byte for comparison */
*address = 0x5050;
/* Clear Status registers command */
*address = 0xFFFF;
/* Write FFH after last operation to reset device to read array mode.
return (GSR);
}
```

292126-22

```

ASM86 ASSEMBLY LANGUAGE DRIVERS
=====
; Copyright Intel Corporation, 1993
; EXAMPLE ASM86 Drivers for the 28F016SA Flash memory component
; Original Author : Patrick Killelea, Intel Corporation
; Revised By : Taylor Gautier
;
; Revision 2.0, September 26, 1994
;
; NOTE:
; The code assumes 32-bit flat model protected mode for simplicity.
; i.e. ES contains 0 and EDI accesses the entire memory space.
=====

TEXT    segment byte    public  'CODE'
        assume cs:TEXT

; Following is the structure by which all parameters are passed.
params STRUCT
        erase_addr        DD      ?      ; base of block or device to
                                         ; erase
        write_addr        DD      ?      ; address to write to
        write_base        DD      ?      ; base address of block written
                                         ; to
        read_addr         DD      ?      ; address to read from
        read_base         DD      ?      ; base address of block read from
        lock_addr         DD      ?      ; base address of block to lock
        data_addr         DD      ?      ; address of data to write
        data              DW      ?      ; data word to write
        pagebuffer_start_addr DB      ?      ; start address in page buffer
        word_count        DW      ?      ; number of words for a multiple
                                         ; read/write
params ENDS

=====
; Defines
=====
;
;
; Error Codes
;
=====
NO_ERROR          DW      0
VPP_LOW           DW      1
OP_ABORTED        DW      2
BLOCK_LOCKED      DW      3
COMMAND_SEQ_ERROR DW      4
WP_LOW            DW      5

;
; Error Codes
;
=====
RYBY_ENABLE_TO_LEVEL DW      1
RYBY_PULSE_ON_WRITE DW      2
RYBY_PULSE_ON_ERASE DW      3
RYBY_DISABLE       DW      4

;
; MACRO set_pin
; This macro pushes parameters needed for the set_pin routine, calls

```

292126-23

```
; set_pin, and then pops those parameters. set_pin is an implementation-
; dependent function which sets a given pin on the standard 28F016SA
; pinout HIGH = 1 or LOW = 0.
;
; Data needed at the beginning of this macro:
; pin: 28F016SA pin number
; level: level to set pin
; Trashes : CX
;=====
MACRO set_pin pin, level
    push pin                      ; Push pin number
    push level                     ; Push logic level of pin
    call near ptr set_pin          ; Call set_pin
    pop CX                         ; Pop off parameters
    pop CX
ENDM
;=====
; MACRO BSROFF
; This macro takes a pointer and increments it by two bytes. Use this
; macro for obtaining the offset to the BSR from a block base address
;=====
MACRO BSROFF pointer
    add pointer, 2                 ; BSR is 2 bytes above base
                                    ; address
ENDM
;=====
; MACRO GSROFF
; This macro takes a pointer and increments it by four bytes. Use this
; macro for obtaining the offset to the GSR from a block base address
;=====
MACRO GSROFF pointer
    add pointer, 4                 ; GSR is 4 bytes above base
                                    ; address
ENDM
;=====
; MACRO GSRBSROFF
; This macro takes a pointer and increments it by two bytes. Use this
; macro for obtaining the offset to the GSR from the BSR
;=====
MACRO GSRBSROFF pointer
    add pointer, 2                 ; GSR is 2 bytes from BSR
ENDM
;=====
; MACRO BSRGSROFF
; This macro takes a pointer and subtracts it by two bytes. Use this
; macro for obtaining the offset to the BSR from the GSR
;=====
MACRO BSRGSROFF pointer
    sub pointer, 2                 ; BSR is 2 bytes below GSR
ENDM
```

292126-24

```
=====
; PROCEDURE    CSR_word_byte_writes
; This procedure writes a byte to the 28F016SA. It also works with a the
28F008SA.
; Param fields needed:
;           params.data: data word to be written
;           params.write_addr: offset of 28F016SA address to write
; Output:      BX: CSR, duplicated in both high and low bytes
=====
CSR_word_byte_writes    proc    near
    mov     EDI,params.write_addr
    mov     ES:[EDI],1010H           ; Write To Flash command
    mov     ES:[EDI],params.data
    ; Write data to 28F016SA.

WSM_busy1:
    mov     AX,ES:[EDI]           ; Read CSR
    test    AX,80H                ; Look at CSR.7.
    jz      short WSM_busy1      ; Loop while CSR.7 = 0.
    ; Poll CSR until CSR.7 = 1, indicating that WSM is ready.

    mov     BX,AX                ; Return CSR in BX.
    mov     ES:[EDI],5050H          ; Clear Status Registers command
    mov     ES:[EDI],FFFFH          ; Reset device to read array mode
    ret
CSR_word_byte_writes    endp
```

292126-25

```
=====
; PROCEDURE    CSR_block_erase
; This procedure erases a 64K byte block on the 28F016SA.
; It also works with a pair of 28F008SAs.
; Param fields needed:
;           erase_address: offset of base of 28F016SA block to erase
; Output      AX: CSR, duplicated in both high and low bytes
=====
CSR_block_erase    proc    near
    mov     EDI,params.erase_addr
    mov     ES:[EDI],2020H           ; Block Erase command
    mov     ES:[EDI],D0D0H           ; Erase Confirm command
    mov     ES:[EDI],D0D0H           ; Resume Command per latest
                                    ; errata update
; Note that it is not strictly necessary to write an erase command to
; the base of a block; any address within the block will do.

WSM_busy2:
    mov     AX,ES:[EDI]             ; Read CSR.
    test    AX,80H                 ; If CSR.7 = 0, test sets ZF.
; System may issue an erase suspend command here to read data from a
; different block
    jz      short WSM_busy2       ; Loop while ZF is set.
; Poll CSR until CSR.7 = 1, indicating that WSM is ready.

    mov     ES:[EDI],5050H           ; Clear Status Registers command
    mov     ES:[EDI],FFFFH           ; Reset device to read array mode
    ret                            ; Return to calling routine
                                    ; CSR is already in AX

CSR_block_erase endp
```

292126-26

```

=====
; PROCEDURE    CSR_erase_suspend_to_read
; This procedure suspends an erase operation to do a read.
; It also works with a pair of 28F008SAs.
; It assumes that erase is underway.
; Param fields needed:
;           params.erase_addr: offset of 28F016SA block to erase
;           params.read_addr: offset of 28F016SA address to read
; Output:      BX: CSR, duplicated in both high and low bytes
;           CX: data read from the address in params.read_addr
=====
CSR_erase_suspend_to_read proc near
    mov    EDI,params.erase_addr           ; Set up offset of erase address.
    mov    ES:[EDI],B0B0H                 ; Erase Suspend command

    WSM_busy3:
        mov    AX,ES:[EDI]                 ; Read CSR from any address.
        test   AX,80H
        jz     short WSM_busy3
        ; Poll CSR until CSR.7 = 1, indicating that WSM is ready.

        test   AX,40H                   ; test CSR.6
        pushf
        ; save result for action later

        mov    EDI,params.read_addr      ; Set up offset of read address.
        mov    ES:[EDI],FFFFH           ; Read Flash command
        mov    CX,ES:[EDI]              ; Do actual read; put result in
                                       ; CX.
        ; Arbitrary number of reads can be done here.

        popf
        jz     short no_resume_command ; get back the result of CSR.6
                                       ; only resume if operation
                                       ; suspended
        mov    ES:[EDI],D0D0H           ; Erase Resume command

    no_resume_command:
        mov    ES:[EDI],7070H           ; Read CSR command
        mov    BX,ES:[EDI]              ; Read CSR from any address.
                                       ; Return CSR in BX.
        ret
CSR_erase_suspend_to_read endp

```

292126-27

```

=====
; PROCEDURE      lock_block
; This procedure locks a block on the 28F016SA.
; Param fields needed:
;           params.lock_addr: offset of base of 28F016SA block to lock
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, DX: trash
=====
lock_block      proc    near

    mov     EDI,params.lock_addr           ; Set up offset of address.
    mov     ES:[EDI],7171H                 ; Read ESR command
    GSROFF EDI                         ; Point EDI to GSR

q_unavailable:
    mov     AX,ES:[EDI]
    test    AX,08H
    jnz     short q_unavailable
; Poll GSR while GSR.3 = 1, indicating queue unavailable.

    set_pin 56,1                         ; Disable write protection.
    set_pin 15,1                         ; Enable Vpp
; Wait for ramp if necessary.
    mov     ES:[EDI],7777H                 ; Lock Block command
    mov     ES:[EDI],D0D0H                 ; Confirmation command
    mov     ES:[EDI],7171H                 ; Read ESR command

WSM_busy4:
    mov     AX,ES:[EDI]                  ; Read GSR
    test    AX,80H
    jz      short WSM_busy4
; Poll GSR while GSR.7 = 0, indicating WSM_busy.

    mov     BH,AH                         ; Store GSR
; Look at BSR.6 to see if block successfully locked.
    BSRGSROFF EDI                      ; Point EDI to BSR from GSR
    mov     AX,ES:[EDI]                  ; Read BSR
    mov     BL,AL                         ; Store BSR
    mov     ES:[EDI],5050H                 ; Clear Status Registers command
    mov     ES:[EDI],FFFFH                 ; Reset device to read array mode
    ret
lock_block      endp

```

292126-28

```

=====
; PROCEDURE      lock_status_upload_to_BSR
; This procedure uploads status information into the ESR from non-volatile
; status bits.
; Param fields needed:
;           params.lock_addr: offset of 28F016SA device
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, CX, DX: trash
=====
lock_status_upload_to_BSR proc      near
    mov    EDI,params.lock_addr
    mov    ES:[EDI],7171H           ; Read ESR command.
    GSROFF EDI                  ; Point EDI to GSR

q_unavailable1:
    mov    AX,ES:[EDI]           ; Read GSR
    test   AX,08H
    jnz    short q_unavailable1
    ; Poll GSR while GSR.3 = 1, indicating queue unavailable.

    mov    ES:[EDI],9797H           ; Lock-status Upload command
    mov    ES:[EDI],D0D0H           ; Confirmation command
    mov    ES:[EDI],7171H           ; Read ESR command

WSM_busy5:
    mov    AX,ES:[EDI]           ; Read GSR
    test   AX,80H
    jz     short WSM_busy5
    ; Poll GSR while GSR.7 = 0, indicating WSM_busy

    mov    AX, ES:[EDI]           ; Read GSR
    mov    BH, AL                 ; Store in high byte of BX
    BSRGSROFF EDI               ; Point EDI to BSR from GSR
    mov    AX,ES:[EDI]           ; Read BSR
    mov    BL, AL                 ; Store BSR
    mov    ES:[EDI],5050H           ; Clear Status Registers command
    mov    ES:[EDI],FFFFH           ; Reset device to read array mode
    ret
lock_status_upload_to_BSR endp

```

292126-29

```

=====
; PROCEDURE      ESR_word_write
; This procedure writes a word to the 28F016SA.
; Param fields needed:
;           params.write_base: offset of base of 28F016SA block to write
;           params.data: data word to write
;           params.write_addr: offset of 28F016SA address to write
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, BX, CX, : trash
=====
ESR_word_write proc    near
    push   SI
    mov    EDI,params.write_addr           ; Set up offset of write address.
    mov    ES:[EDI], 7171H                 ; Read Extended Status Registers
                                            ; command
    mov    EBX,params.write_base          ; Get base of block to write
    BSROFF EDI
    mov    CX, params.word_count          ; params.data should be a pointer
    mov    SI, params.data                ; to an array of data to write to
                                            ; the flash array
q_unavailable2:
    mov    AX,ES:[EBX]                   ; Read BSR
    test   AX,08H
    jne    short q_unavailable2
;Loop while BSR.3 of target address = 1, meaning queue full.

    mov    ES:[EDI], 1010H               ; Write Byte command
    movsw
    loop   q_unavailable2
    mov    EDI,params.write_base          ; loop until CX = 0
                                            ; Set up offset of block base
                                            ; in case we wrote to the end of
                                            ; the device, in which case EDI
                                            ; will now be 2 bytes past the
                                            ; device
    mov    ES:[EDI],7171H                ; Read ESR command
    BSROFF EDI                         ; Point EDI to BSR

block_busy:
    mov    AX,ES:[EDI]                  ; Read BSR
    test   AX,0080H
    jz     short block_busy
;Poll BSR while BSR.7 of target address is 0, meaning block busy

    mov    BL,AL                         ; Store BSR in BL
    GSRBSROFF   EDI                     ; Point EDI to GSR from BSR
    mov    BH,ES:[EDI]                  ; Read GSR and store in BH
    mov    ES:[EDI],5050H                ; Clear Status Registers command
    mov    ES:[EDI], 0FFFFH              ; Reset device to read array mode
    pop    SI
    ret                             ; Return to calling routine.
ESR_word_write endp

```

292126-30

```

=====
; PROCEDURE      two_byte_write
; This routine is used when BYTE# is low, i.e. the 28F016SA
; is in byte mode, to emulate a word write.
; Param fields needed: (assume existence of byte fields data_high and
; data_low)
;           params.write_base: offset of base of 28F016SA block to write
;           params.data_high: high data byte to write
;           params.data_low: low data byte to write
;           params.write_addr: offset of 28F016SA address to write
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, CX, DX: trash
=====
two_byte_write proc    near

    mov     EDI,params.write_base      ; Set up offset of address.
    mov     ES:[EDI],0071H            ; Read ESR command
    BSROFF EDI                    ; Point EDI to BSR
    mov     CX, params.word_count  ; use word_count as byte_count

q_unavailable3:
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,08H
    jnz    short q_unavailable3
    ; Loop while BSR.3 of target address is 1, meaning queue full.

    mov     ES:[EDI],00FBH          ; Two-byte write command
    ; Write low byte of data word
    mov     EDI,params.write_addr  ; Set up offset of address.
    mov     ES:[EDI],params.data_high
    mov     ES:[EDI],params.data_low

    ; 28F016SA automatically loads alternate byte of data register and
    ; initiates write. Now we check for successful completion.

    mov     ES:[EDI],7171H          ; Read ESR command
    mov     EDI,params.write_base
    BSROFF EDI                    ; Point EDI to BSR

block_busy2:
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,80H
    jz     short block_busy2
    ; Poll BSR while BSR.7 of target address is 0, meaning block busy.

    mov     BH,ES:[EDI]            ; Read BSR
    GSRBSROFF EDI                ; Point EDI to GSR from BSR
    mov     BL,ES:[EDI]            ; Read and store GSR
    mov     ES:[EDI],5050H          ; Clear Status Registers command
    ret

two_byte_write endp

```

292126-31

```
=====
; PROCEDURE ESR_pagebuffer_write
; This procedure writes from page buffer to flash.
; Param fields needed:
;           params.write_base: offset of base of 28F016SA block to write
;           params.pagebuffer_word_count: number of words to write to flash
;           params.write_addr: offset of 28F016SA address to write
; Output:    BX: GSR in high byte and BSR in low byte of BX
;           AX, CX, DX: trash
=====
ESR_pagebuffer_write proc near

    push    SI                      ; Save old SI.
    mov     SI,params.word_count    ; Use SI to count words.

; Address is where in 28F016SA flash array to begin write. The lowest
; byte of this must be identical to the start address in the page buffer.
; Low byte of byte_count must be 256 or fewer, high must be 0.
; High byte exists for future Page Buffer expandability.
    mov     EDI,params.write_base    ; Offset of block base address.
    mov     ES:[EDI],7171H          ; Read ESR command
    BSROFF EDI

q_unavailable4:
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,8
    jne   short q_unavailable4
; Loop while BSR.3 of target address is 1, meaning queue full.

    mov     ES:[EDI],0C0CH          ; Page Buffer Write command
    mov     ES:[EDI],SI              ; Write count
; Only A0 valid here; low or high byte loaded depending on A0.
    mov     ES:[EDI], 0
; A0 internally complemented; alternate byte loads; write starts.
    mov     ES:[EDI],7171H          ; Read ESR command

block_busy3:
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,80H
    jz    short block_busy3
; Loop while BSR.7 of target address is 0, meaning block busy.

    mov     BL,ES:[EDI]            ; Read BSR
    GSRBSROFF EDI                ; point EDI to GSR from BSR
    mov     BH,ES:[EDI]            ; Read GSR
    mov     ES:[EDI],5050H          ; Clear Status Registers command
    mov     ES:[EDI], 0FFFFH        ; Reset device to read array mode
    pop    SI                      ; Retrieve old SI.
    ret                           ; Return to calling routine.

ESR_pagebuffer_write endp
```

292126-32

```

=====
; PROCEDURE      ESR_block_erase
; This procedure erases a block on the 28F016SA.
; Param fields needed:
;           params.erase_addr: offset of base of 28F016SA block to erase
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, DX: trash
=====
ESR_block_erase      proc    near
    mov     EDI,params.erase_addr           ; Set up offset of address.
    mov     ES:[EDI],7171H                 ; Read ESR command
    BSROFF EDI                         ; point EDI to BSR

q_unavailable5:
    mov     AX,ES:[EDI]                  ; Read BSR
    test    AX,08H
    jne     short q_unavailable5
    ; Loop while BSR.3 of target address is 1, meaning queue full.

    mov     ES:[EDI],2020H               ; Block Erase command
    mov     ES:[EDI],D0D0H               ; Confirm command
    mov     ES:[EDI],D0D0H               ; Resume command, per latest
    ; errata update
    mov     ES:[EDI],7171H               ; Read ESR command
    ;Note that EDI still points to BSR

block_busy4:
    mov     AX,ES:[EDI]                  ; Read BSR
    test    AX,80H
    jz      short block_busy4
    ;Loop while BSR.7 of target address = 0, i.e. block busy.

    mov     BL,AL                      ; Store BSR in BL.
    GSRBSROFF EDI                   ; point EDI to GSR from BSR
    mov     BH,ES:[EDI]                ; Read GSR, store in BH
    mov     ES:[EDI],5050H               ; Clear Status Registers command
    mov     ES:[EDI],0FFFFH              ; Reset device to read array mode
    ret
ESR_block_erase      endp

```

292126-33

```
=====
; PROCEDURE ESR_erase_all_unlocked_blocks
; This procedure erases all the unlocked blocks on a 28F016SA.
; params.erase_addr: offset of base of device to erase
; Output:    CX: GSR in both high byte and low byte
;             BX: Failure list
;             AX, DX: trash
=====
ESR_erase_all_unlocked_blocks proc    near
    push    SI                      ; Save old SI.
    mov     EDI,params.erase_addr    ; erase_addr should be set to
                                    ; the device address
    mov     ES:[EDI],7171H          ; Read ESR command
    BSROFF EDI                    ; point EDI to BSR

q_unavailable6:
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,08H
    jnz    short q_unavailable6
    ; Poll BSR while BSR.3 of target address is 1, meaning queue full.

    mov     ES:[EDI],A7A7H          ; Full-chip Erase command
    mov     ES:[EDI],D0D0H          ; Confirm command
    mov     ES:[EDI],7171H          ; Read ESR command
    GSRBSROFF EDI                ; Point EDI to GSR from BSR

WSM_busy6:
    mov     AX,ES:[EDI]            ; Read GSR
    test   AX,80H
    jz     short WSM_busy6
    ;loop until GSR.7 indicates WSM is ready

    mov     AX,ES:[EDI]            ; Read GSR for operation success
    test   AX,20H
    jz     short operation_successful

    ; If GSR.5 = 1, meaning that the operation was unsuccessful,
    ; go through blocks, looking for the ones which didn't erase.
    xor    SI,SI                  ; Clear SI.
    xor    EBX, EBX                ; Clear EBX for failure list
    mov     EDX, 1                  ; use EDX as mask to set failures
    mov     EDI, params.erase_addr ; start at the beginning of the
                                    ; device
    mov     CX, 32                  ; 32 blocks in 28F016SA
    BSRGSROFF EDI                ; point EDI to BSR from GSR

look_for_bad_erase:
    ; Looking at each BSR.3 for operation success.
    mov     AX,ES:[EDI]            ; Read BSR
    test   AX,08H
    jz     short ok_erased

    ; record number of bad block here
    or     EBX, EDX

ok_erased:
    shl    EDX
```

292126-34

```
    add    EDI, 10000H          ; Increment EDI to next block
loop    look_for_bad_erase

operation_successful:
    mov    EDI, params.erase_address ; reset EDI to device address
    GSROFF EDI                   ; point EDI to GSR
    mov    BX, ES:[EDI]
    mov    ES:[EDI],5050H          ; Clear Status Registers command
    mov    ES:[EDI], 0FFFFH         ; Reset device to read array mode
    pop    SI
    ret                           ; Return to calling routine.

ESR_erase_all_unlocked_blocks endp
```

292126-35

```

=====
; PROCEDURE    ESR_suspend_to_read_array
; This procedure suspends an erase on the 28F016SA.
; Param fields needed:
;           params.erase_addr: offset of base of erasing 28F016SA block
;           params.read_addr: offset of 28F016SA address to read
; Output:      BX: GSR in high byte and BSR in low byte (of erase block)
;           CX: data read from flash
;           AX, DX: trash
=====
ESR_suspend_to_read_array proc      near
    mov    EDI, params.erase_addr
    BSROFF EDI                      ; point EDI to BSR
    mov    ES:[EDI], 7171H           ; Read ESR command

block_busy5:
    mov    AX, ES:[EDI]             ; Read BSR
    test   AX, 80H
    jz    block_busy5
    ; Loop if BSR.7 of target address is 0, meaning block busy.

    mov    ES:[EDI], 0B0B0H           ; Operation Suspend command
    GSRBSROFF EDI                ; Point EDI to GSR from BSR

WSM_busy7:
    mov    AX, ES:[EDI]             ; Read GSR
    test   AX, 80H
    jz    short WSM_busy7
    ; Poll GSR until GSR.7 indicates WSM is ready.

    test   AX, 40H
    pushf
    mov    EDI, params.read_addr   ; store result for later
    mov    ES:[EDI], FFFFH          ; Set up offset of read address.
    mov    CX, ES:[EDI]            ; Write Read Flash Array command
    mov    CX, ES:[EDI]            ; Read the data

    mov    EDI, params.erase_addr  ; Set up offset of erase address.
    popf
    jz    short nothing_suspended
    ; If GSR.6 indicates an operation was suspended on this device,
    ; then resume the operation.
    mov    ES:[EDI], 0D0D0H           ; Resume command

nothing_suspended:
    mov    BH, AH                  ; Store GSR in BH.
    sub    EDI, 2                  ; Move EDI down to read BSR.
    mov    BL, ES:[EDI]            ; Read BSR and store in BL
    mov    ES:[EDI], 5050H          ; Clear Status Registers command
    mov    ES:[EDI], 0FFFFH          ; Reset device to read array mode
    ret                           ; Return to calling routine.

ESR_suspend_to_read_array endp

```

292126-36

```

=====
; PROCEDURE      ESR_automatic_erase_suspend_to_write
; This procedure writes to one block while another is erasing.
; Param fields needed:
;           params.data: data word to write to 28F016SA
;           params.erase_addr: offset of 28F016SA address to erase
;           params.write_addr: offset of 28F016SA address to write
; Output:      BX: GSR in high byte and BSR in low byte
;           AX, DX: trash
=====
ESR_automatic_erase_suspend_to_write proc    near
    mov    EDI,params.erase_addr           ; Set up offset of address.
    mov    ES:[EDI],7171H                 ; Read ESR command
    BSROFF EDI                         ; point EDI to BSR

q_unavailable7:
    mov    AX,ES:[EDI]                  ; Read BSR
    test   AX,08H
    jnz    short q_unavailable6
    ; Loop while BSR.3 of target address is 1, meaning queue full.

    mov    ES:[EDI],2020H               ; Write Erase Block command
    mov    ES:[EDI],D0D0H               ; Erase Confirm command
    mov    EDI,params.write_addr       ; Set up offset of address.
    mov    ES:[EDI],4040H               ; Write Word command
    mov    ES:[EDI],params.data        ; Write actual data

    ; Erase will suspend, write will take place, then erase resumes.

    mov    EDI,params.erase_addr       ; Set up offset of address.
    mov    ES:[EDI],7171H               ; Read ESR command
    BSROFF EDI                         ; point EDI to BSR

block_busy6:
    mov    AX, ES:[EDI]
    test   AX,80H
    jz     short block_busy6
    ; Loop while BSR.7 of target address is 0, meaning block busy.

    mov    BH,ES:[EDI]                  ; Read BSR
    GSRBSROFF EDI
    mov    BL,ES:[EDI]                  ; Read and store GSR
    mov    ES:[EDI],5050H               ; Clear Status Registers command
    mov    ES:[EDI],0FFFFH              ; Reset device to read array mode
    ret
ESR_automatic_erase_suspend_to_write endp

```

292126-37

```

=====
; PROCEDURE    ESR_full_status_check_for_data_write
; This procedure performs a full status check of the Extended Status
; Register
; Param fields needed:
;           params.write_base: offset of base of device
; Output:    CX : errorcode
;           AX, BX: trash
=====
ESR_full_status_check_for_data_write proc near
    mov    EDI, params.write_base
    mov    ES:[EDI], 7171H           ; Read ESR command
    GSROFF EDI                   ; Point EDI to GSR

WSM_busy8:
    mov    AX,ES:[EDI]             ; Read GSR
    test   AX,80H
    jz     short WSM_busy8
    ; Poll GSR while GSR.7 = 0, indicating WSM busy.

    BSRGSROFF EDI               ; Point EDI to BSR from GSR
    mov    AX,ES:[EDI]
    test   AX, 04H                ; BSR.2 = 1 indicates VPP_LOW
    jz     vpp_high

    mov    CX, VPP_LOW
    jmp    cont

vpp_high:
    test   AX, 10H                ; BSR.4 = 1 indicates operation
    jz     op_not_aborted
    ; was aborted

    mov    CX, OP_ABORTED
    jmp    cont

op_not_aborted:
    get_pin WPB                  ; get_pin returns output in BX
    cmp    BX, 00H
    je     wpb_high
    ; no error if WPB is low

    jmp    no_error

wpb_high:
    test   AX, 40H                ; BSR.6 indicates BLOCK_LOCKED
    jz     no_error

    mov    CX, BLOCK_LOCKED
    jmp    cont

no_error:
    mov    CX, NO_ERROR

cont:
    GSRBSROFF EDI               ; Point EDI to GSR from BSR

WSM_busy9:
    mov    AX, ES:[EDI]

```

292126-38

```
test    AX, 80H
jz     WSM_busy9
; Poll GSR while GSR.7 = 0, indicating WSM busy.

mov     ES:[EDI],5050H           ; Clear Status Registers command
ret
ESR_full_status_check_for_data_write endp
```

292126-39

```

=====
; PROCEDURE    ESR_full_status_check_for_erase
; This procedure performs a full status check of the Extended Status
; Register
; Param fields needed:
;           params.write_base: offset of base of device
; Output:    CX : errorcode
;           AX, BX: trash
=====
ESR_full_status_check_for_erase proc near
    mov    CX, NO_ERROR
    mov    EDI, params.write_base
    mov    ES:[EDI], 7171H           ; Read ESR command
    GSROFF EDI                   ; Point EDI to GSR

WSM_busy10:
    mov    AX,ES:[EDI]             ; Read GSR
    test   AX,80H
    jz     short WSM_busy10
    ; Poll GSR while GSR.7 = 0, indicating WSM busy.

    BSRGSROFF EDI               ; Point EDI to BSR from GSR
    mov    AX,ES:[EDI]
    test   AX, 04H                ; BSR.2 = 1 indicates VPP_LOW
    jz     vpp_high

    mov    CX, VPP_LOW
    jmp    cont

vpp_high:
    test   AX, 10H                ; BSR.4 = 1 indicates operation
    jz     op_not_aborted         ; was aborted

    mov    CX, OP_ABORTED
    jmp    cont

op_not_aborted:
    get_pin WPB                  ; get_pin returns output in BX
    cmp    BX, 00H
    jne    no_error               ; BSR.6 and WPB LOW indicates
    test   AX, 40H                ; BLOCK_LOCKED
    jz     no_error

    mov    CX, BLOCK_LOCKED
    jmp    cont

no_error:
    mov    ES:[EDI], 7070H          ; Read CSR command
    mov    AX, ES:[EDI]
    test   AX, 10H                ; CSR.4 and CSR.5 indicate
    jz     cont                   ; command sequence error
    test   AX, 20H
    jz     cont
    mov    CX, COMMAND_SEQ_ERROR

cont:
    mov    ES:[EDI], 7171H          ; Read ESR command

```

292126-40

```
; EDI still points to GSR

WSM_busy11:
    mov     AX,ES:[EDI]                      ; Read GSR
    test    AX,80H
    jz     short WSM_busy11
    ; Poll GSR while GSR.7 = 0, indicating WSM busy.

    mov     ES:[EDI],5050H                  ; Clear Status Registers command
    ret
ESR_full_status_check_for_erase endp
```

292126-41

```
=====
; PROCEDURE    single_load_to_pagebuffer
; This procedure loads a single byte or word to a page buffer.
; Param fields needed:
;           params.write_base: offset of base of device
;           params.data: data to be written to page buffer
;           params.pagebuffer_start_addr: byte giving pb location to write
; Output:    AX: trash
=====
single_pagebuffer_load proc    near
    mov     EDI,params.write_base           ; Set up offset of base address.
    mov     ES:[EDI],7171H                 ; Read ESR command
    GSROFF EDI                         ; point EDI to GSR

wait_for_pb:
    mov     AX,ES:[EDI]                  ; Read GSR
    test   AX,04H
    jz     short wait_for_pb
    ; Poll GSR until GSR.2 indicates that a page buffer is available

    mov     ES:[EDI],7474H               ; Single PB Write command
    ; Actual write to page buffer.
    add     EDI,params.pagebuffer_start_addr ; Set up offset of
                                              ; address.
    mov     ES:[EDI],params.data
    ; BP+4 is location in pb to write.
    ret                           ; Return to calling routine.
single_load_to_pagebuffer endp
```

292126-42

```

=====
; PROCEDURE sequential_load_to_pagebuffer
; This procedure loads the page buffer.
; Param fields needed:
;           params.write_addr: offset of origin of device
;           params.data_addr: pointer to data to be written to pg buffer
;           params.pagebuffer_word_count: number of words to write to pg
; buffer
;           params.pagebuffer_start_addr: starting pb address of data to
; write
; Output:      AX, BX, DX: trash
=====
sequential_load_to_pagebuffer proc    near

    sub    SP,2                      ; Set aside room for counter.
    mov    byte ptr [BP-1],0          ; Clear high byte of counter
                                      ; word.
    push   SI                      ; Save old SI.
    mov    SI,word_count            ; Put # of words to write in SI.
    ; SP+6 must be 128 or fewer, SP+7 must be 0.
    ; High byte exists for future Page Buffer expandability.
    mov    EDI,params.write_addr    ; Set up offset of device
                                      ; address.
    mov    ES:[EDI],7171H           ; Read ESR command
    ; Commands to control entire 28F016SA do not need to be written to any
    ; particular address.
    GSROFF EDI                   ; point EDI to GSR

wait_for_pb2:
    mov    AX,ES:[EDI]              ; Read GSR
    test   AX,4
    jz     short wait_for_pb2
    ; Poll GSR until GSR.2 indicates that a page buffer is available.

    mov    ES:[EDI],E0E0H           ; Sequential Page Buffer Load
                                      ; cmd.
    ; Loads high or low byte of count register, depending on A0.
    mov    ES:[EDI],SI              ; Write
    ; Automatically loads alternate byte of count register.
    mov    ES:[EDI],SI              ; Write

    ; Loop through data, writing to page buffer.
    mov    byte ptr [BP-1],0          ; Load counter.
    jmp    short compare

not_done:
    mov    DX,word ptr [BP-2]        ; Put current val. of counter in
                                      ; DX.
    mov    AL,params.pagebuffer_start_addr ; Get starting address in pb.
    cbw
    add    AX,DX                  ; Convert it to a word.
    cwd
    mov    BP+12,DX                ; Add to get abs. address in pb.
                                      ; Convert AX to a double word.
    mov    BP+10,AX                ; Store segment of pb address
                                      ; (0).
    mov    AX,word ptr [BP-2]        ; Get current value of counter.
    mov    EBX,params.data_addr    ; Get address of where data is.
    add    EBX,AX                  ; Add value of counter to it.

```

292126-43

```
    mov    ES,word ptr [BX]           ; Put data at that address on
    mov    EDI,params.write_base    ; stack.
    mov    ES:[EDI],AX             ; Set up offset of address.
    inc    word ptr [BP-2]          ; Write
    compare:
    mov    AX,word ptr [BP-2]        ; Increment counter.
    cmp    AX,SI                  ; Get current value of counter.
    j1    short not_done          ; Compare to final value.

; End of loop.
    pop    SI                   ; Retrieve old SI.
    mov    SP,BP                ; Retrieve old SP.
    ret                         ; Return to calling routine.

sequential_load_to_pagebuffer endp
```

292126-44

```

=====
; PROCEDURE      upload_device_information
; This procedure uploads the device revision code into the page buffer.
; Param fields needed:
;           params.write_base: offset of 28F016SA device
; Output:      DX: Device revision number
;           AX, CX: trash
=====
upload_device_information      proc      near
    mov     EDI,params.write_base
    mov     ES:[EDI],7171H           ; Read ESR command.
    inc     EDI                  ; Move EDI up to GSR.
    inc     EDI

q_unavailable8:
    mov     AX,ES:[EDI]           ; Read GSR
    test    AX,8
    jne     short q_unavailable8
    ; Poll GSR while GSR.3 = 1, indicating queue unavailable.

WSM_busy12:
    mov     AX,ES:[EDI]           ; Read GSR
    test    AX,80H
    je      short WSM_busy12
    ; Poll GSR while GSR.7 = 0, indicating WSM busy.

    mov     ES:[EDI],9999H         ; Lock-status Upload command
    mov     ES:[EDI],D0D0H         ; Confirmation command
    mov     ES:[EDI],7171H         ; Read ESR command

WSM_busy13:
    mov     AX,ES:[EDI]           ; Read GSR
    test    AX,80H
    jz      short WSM_busy13
    ; Poll GSR while GSR.7 = 0, indicating WSM_busy

    mov     ES:[EDI],7272H         ; Swap Page Buffer command
    mov     ES:[EDI],7575H         ; Read Page Buffer command
    mov     DX,[params.write_base+3] ; Put revision number in DX
    ; Revision number is 3 words above write_base in page buffer space.
    ; GSR.5 should be checked for operation success before using revision
    ; number.
    ret                          ; Return to calling routine.
upload_device_information endp

```

292126-45

```

=====
; PROCEDURE    RYBY_reconfiguration
; This procedure reconfigures the RY/BY# output mode
; Param fields needed:
;           params.write_base: offset of 28F016SA device
;           params.data: reconfiguration define
; Output:    AX : GSR
=====
RYBY_reconfiguration proc    near
    mov    EDI, params.write_base
    mov    ES:[EDI], 7171H           ; Read ESR command
    GSROFF EDI                   ; Point EDI to GSR

q_unavailable9:
    mov    AX,ES:[EDI]             ; Read GSR
    test   AX,8                  ; test bit 3
    jne    short q_unavailable9

    mov    ES:[EDI], 9696H         ; RY/BY# reconfiguration code
    cmp    params.data, 01
    jne    switch1

    mov    ES:[EDI], 0101H         ; Enable RY/BY# to level mode
    jmp    break

switch1:
    cmp    params.data, 02
    jne    switch2

    mov    ES:[EDI], 0202H         ; Enable RY/BY# to pulse on write
    jmp    break

switch2:
    cmp    params.data, 03
    jne    default

    mov    ES:[EDI], 0303H         ; Enable RY/BY# to pulse on erase
    jmp    break

default:
    mov    ES:[EDI], 0404H         ; Enable RY/BY# to disable
break:
    mov    ES:[EDI], 7171H         ; Read ESR command

WSM_busy14:
    mov    AX,ES:[EDI]             ; Read GSR (EDI already points to
    test   AX,80H                 ; GSR)
    jz     short WSM_busy14

    mov    ES:[EDI],5050H           ; Clear Status Registers command
    mov    ES:[EDI],0FFFFFH         ; Reset device to read array mode
RYBY_reconfiguration endp

```

292126-46

```
=====
; PROCEDURE      page_buffer_swap
; This procedure swaps the page buffers.
; Param fields needed:
;           params.write_base: offset of 28F016SA device
; Output:      AX : GSR before operation in high byte, GSR in low
;               byte after operation
=====
page_buffer_swap proc near
    mov    EDI, params.write_base
    mov    ES:[EDI], 7171H           ; Read ESR command
    GSROFF EDI                   ; Point EDI to GSR

    mov    AH,ES:[EDI]             ; Read GSR and store in AH

    mov    ES:[EDI], 7272H           ; Page Buffer Swap command

    mov    AL,ES:[EDI]             ; Read GSR and store in AL
    mov    ES:[EDI],5050H           ; Clear Status Registers command
    mov    ES:[EDI],0FFFFH           ; Reset device to read array mode
page_buffer_swap endp

TEXT    ends
```

292126-47

## APPENDIX A FUNCTION CHANGES

OLD FUNCTION NAME	NEW FUNCTION NAME
compatible_block_erase	CSR_block_erase
compatible_suspend_to_read	CSR_erase_suspend_to_read
compatible_byte_write	CSR_word_byte_writes
ESR_block_erase	N/C
ESR_status_check_after_erase*	ESR_full_status_check_for_erase
ESR_status_check_after_write*	ESR_full_status_check_for_data_write
ESR_suspend_to_read	ESR_suspend_to_read_array
ESR_word_write	N/C
erase_all_unlocked_blocks	ESR_erase_all_unlocked_blocks
lock_block	N/C
status_upload	lock_status_upload_to_BSR
pagebuffer_write_to_flash	ESR_pagebuffer_write
sequential_pagebuffer_load	sequential_load_to_pagebuffer
single_pagebuffer_load	single_load_to_pagebuffer
two_byte_write	N/C
write_during_erase	ESR_automatic_erase_suspend_to_write

**NOTE:**

\*code added in Rev 2.0.



## APPENDIX B

### Glossary of Terms

BSR: Block Status Register. Each BSR reflects the status of its 64KB block.

CSR: Compatible Status Register. The CSR reflects the status of the entire device and is identical in format to the Status Register of the 28F008SA.

EDI: Extended Data Index register on 80386 and higher CPUs.

ESR: Extended Status Registers. The GSR and BSRs.

GSR: Global Status Register. The GSR provides additional information about entire device status.

RY/BY #: Output pin from the 28F016SA indicating status of current operation.

V<sub>PP</sub>: Voltage necessary to program the 28F016SA (12V).

WSM: Write State Machine. On-board processor automating write, erase and other functions.



## APPENDIX C

### ADDITIONAL INFORMATION

Order Number	Document
290489	28F016SA Datasheet
292124	AP-375 Upgrade Considerations from the 28F008SA to the 28F016SA
297372	16-Mbit Flash Product User's Manual
292127	AP-378 System Optimization Using the Enhanced Features of the 28F016SA
294016	ER-33 Flash Memory Technology ETOX IV
290528	28F016SV Datasheet
292144	AP-393 28F016SV Compatibility with 28F016SA

### REVISION HISTORY

Number	Description
001	Original Version
002	Updated Version of C and ASM code, compatible with 28F016SV/XS/XD
003	Added 28F016XS and 28F016XD Feature Set notice